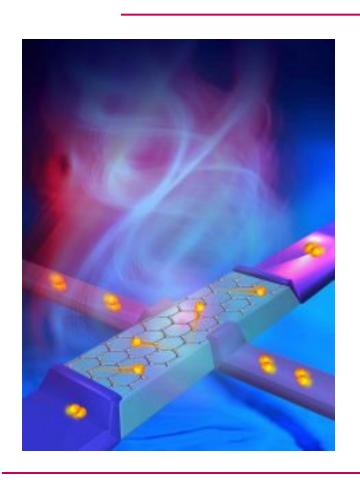
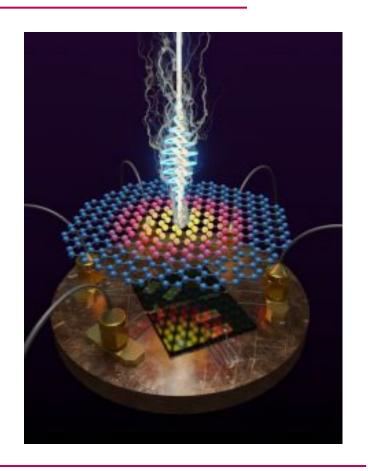
# Developing graphene Josephson junction-based microwave detector



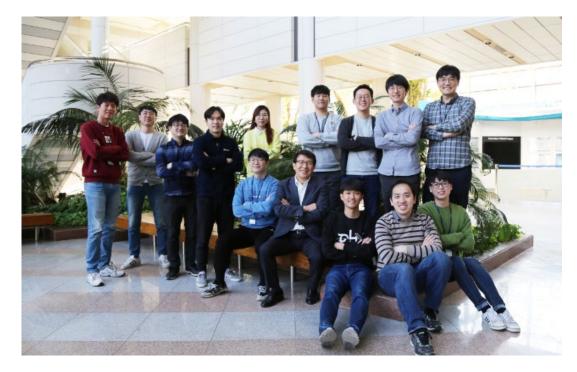
## Gil-Ho Lee

Dept. of Physics, POSTECH, Korea

(https://ghleelab.postech.ac.kr/)



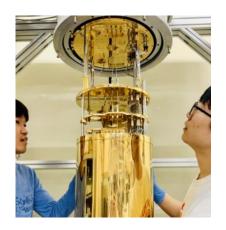
## **Quantum Nano-Electronics Lab in POSTECH**



10 PhD students & 3 postdocs



Nano-fabrication



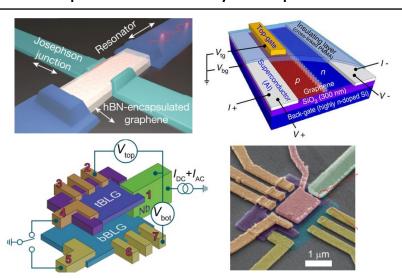
low temperature measurement

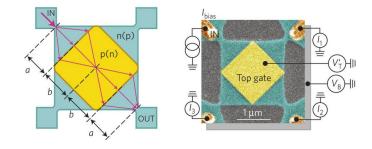


# Research in QNL lab @ POSTECH

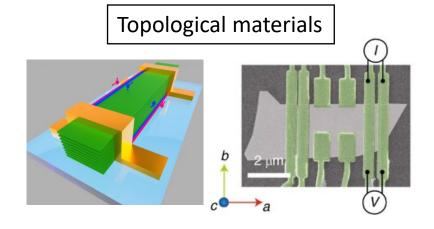
Graphene-Superconductor hybrid quantum devices

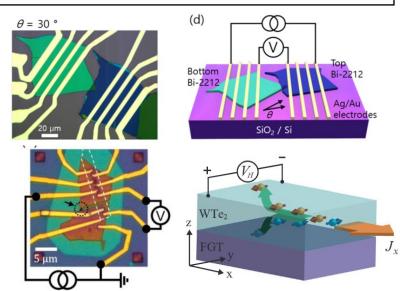
**Dirac Fermionic Optics** 





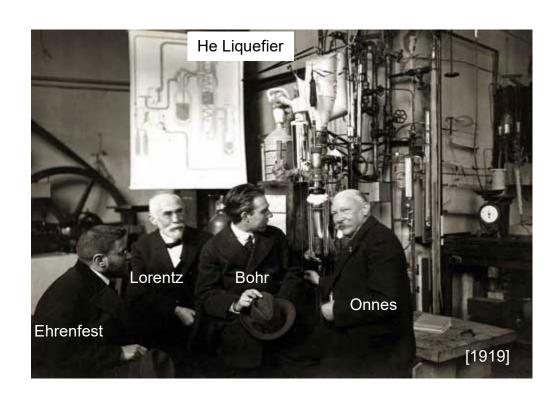
Van der Waals based quantum devices



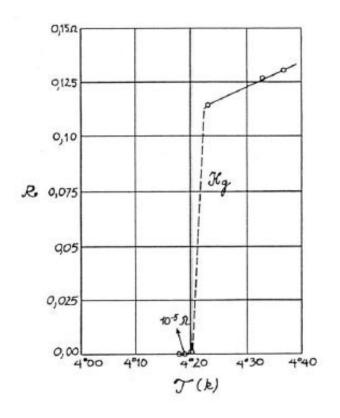




# **Superconductivity**

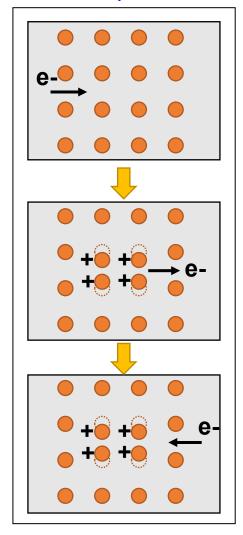


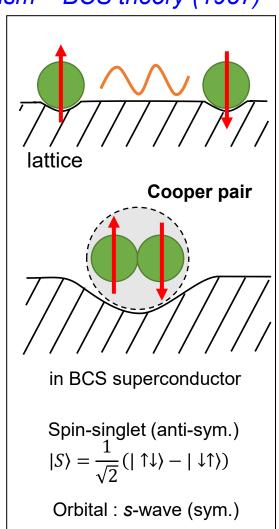
#### Superconductivity of Mercury (1911)



# **Superconductivity: Macroscopic Quantum Phenomena**

#### Microscopic mechanism – BCS theory (1957)





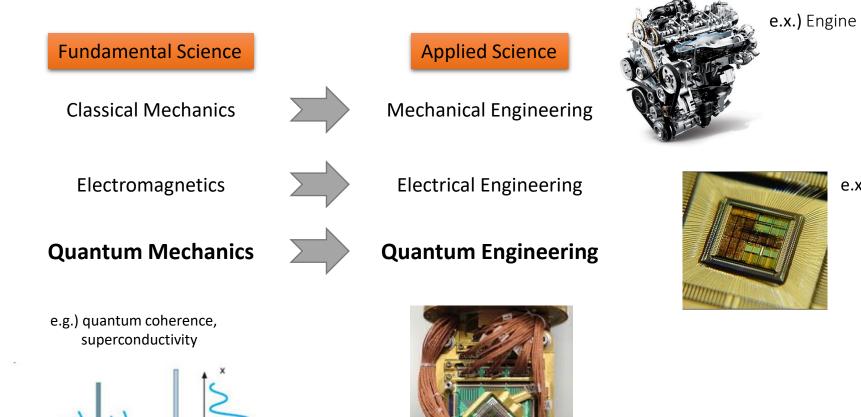
#### Macroscopic quantum phenomena

10<sup>23</sup>-electroncs in superconductor behaves as a single quantum object **BEC** condensate Laser of atoms



## **Quantum Electronics**

- Study of quantum mechanical behavior of electrons in solids

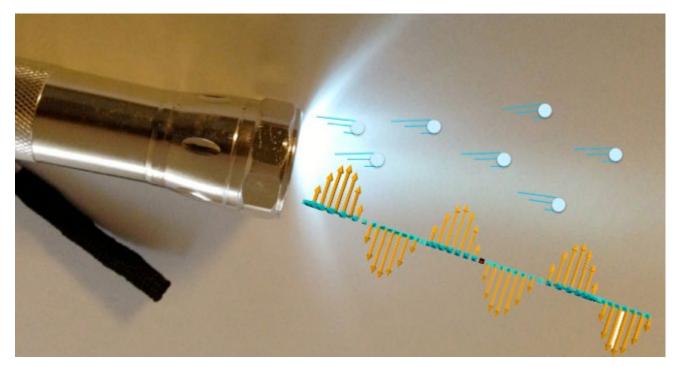


e.x.) Quantum Computers



e.x.) CPU

## Light

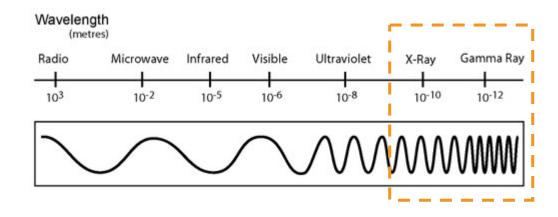




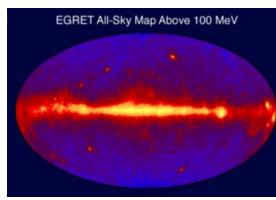
(Photon number, n) = (Light power, P) x (time, t) / (photon energy, hf)

Detecting single photons would be the ultimate detector for light.

# $X/\gamma$ -Ray







Medical X-ray imaging

Gamma ray sky

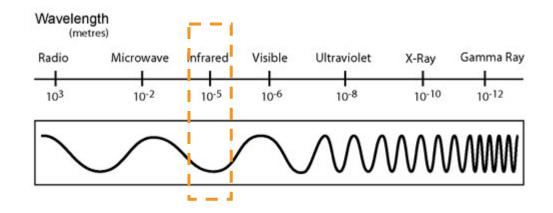
- in  $X/\gamma$ -ray range
  - Medical imaging
  - Material science
  - Astronomy science



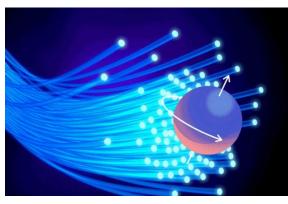
Material Science suing synchrotrons



## Infra-red



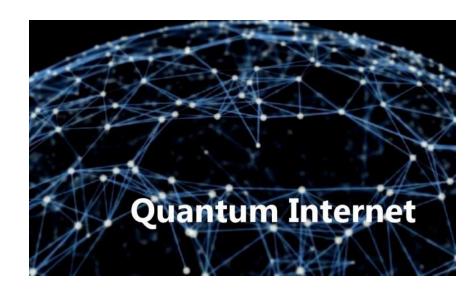




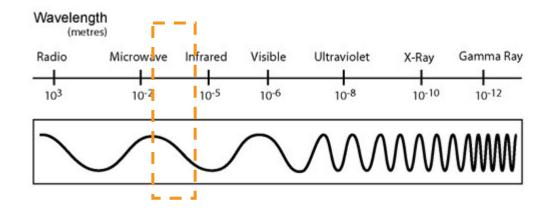
Infrared camera

Optical cable

- in **IR** range
  - optical quantum communication
  - quantum key distribution

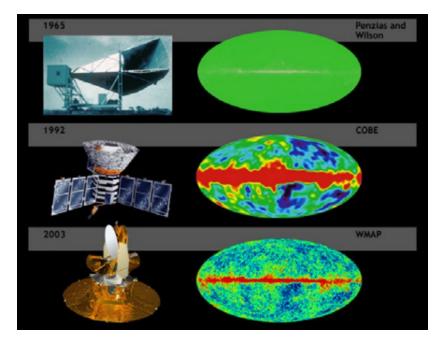


## **Terahertz**

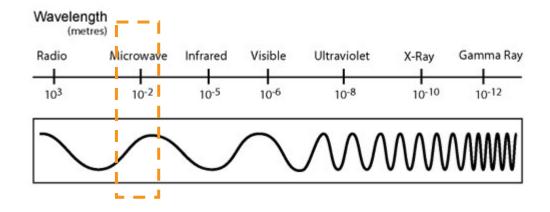




- in **THz** range
  - galaxy formation via cosmic radiation

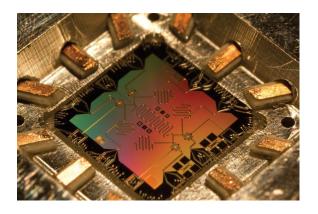


## **Microwave**





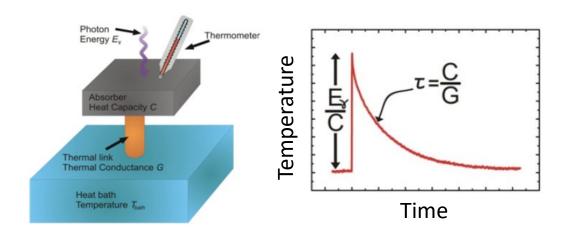
- in **GHz** range
  - remote entanglement of superconducting qubits
  - high-fidelity quantum measurements
  - microwave quantum illumination



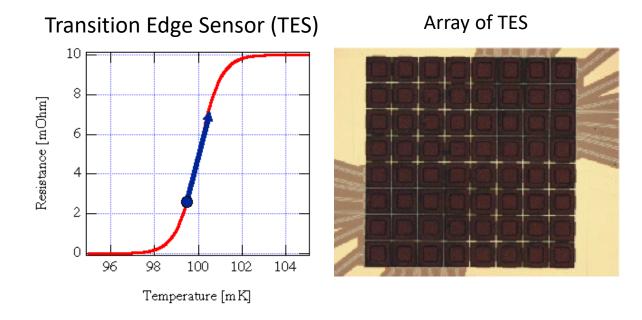


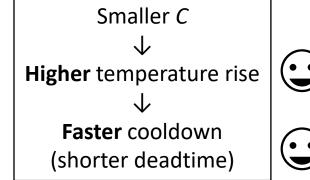
## **Thermal Detector**

- No need to collect electron
- No threshold
- Robust against impurities
- More freedom to choose material



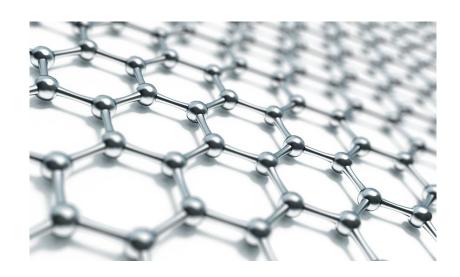
- $E_r$ : Photon energy
- C: Heat capacity
- G: Thermal conductance

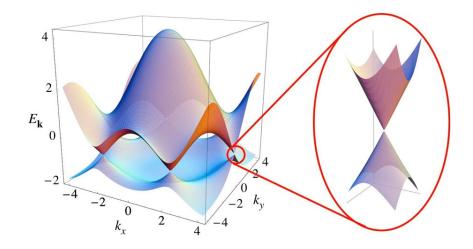






## **Graphene for Sensor**





• Very small electronic heat capacity due vanishing density of state, D(E) near Dirac point (E=0).

$$D(E) = 2|E|A/\pi(\hbar v_F)^2$$

 Faster thermalization, thanks to short el-el scattering time.

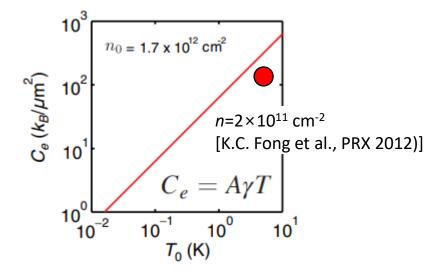
[Nat. Phys. 9, 248 (2013)]

 Broad absorption bandwidth by impedance matching

# Small Electronic Heat Capacity, Ce

Specific heat capacity of monolayer graphene:

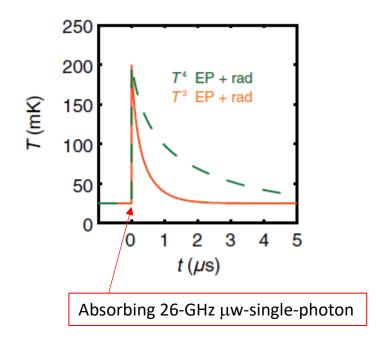
$$C_{\rm e} \sim 10k_{\rm B}/\mu {\rm m}^2$$
 (@  $T$ =0.1 K, n=1.7×10<sup>12</sup> cm<sup>-2</sup>)



Sommerfeld coefficient:

$$\gamma = (4\pi^{5/2}k_B^2 n^{1/2})/(3hv_F)$$
Carrier density

#### Significant heating of electrons!



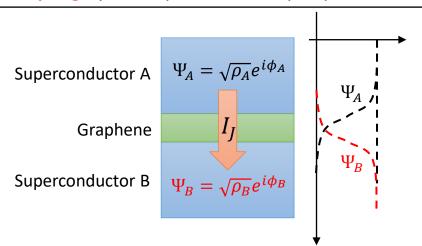
For  $\mu$ w-SPD, we need to detect temperature rise  $\Delta T \sim 200$  mK within  $\tau_{\text{el-ph}} \sim 100$  ns.

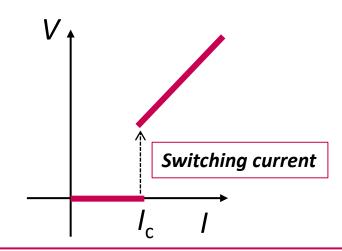
[E.D. Walsh et al., PRApplied 8, 024022 (2017)]



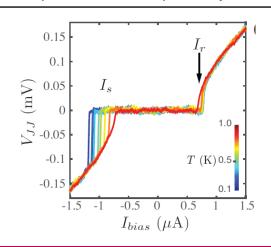
## **Josephson Junction**

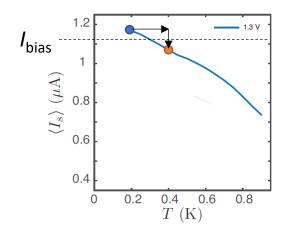
Josephson coupling by overlap of macroscopic quantum wave-functions across junction





#### Al/Graphene/Al Josephson junction,





 Switching current, <*I<sub>s</sub>*>, strongly depends on electron temperature of graphene.

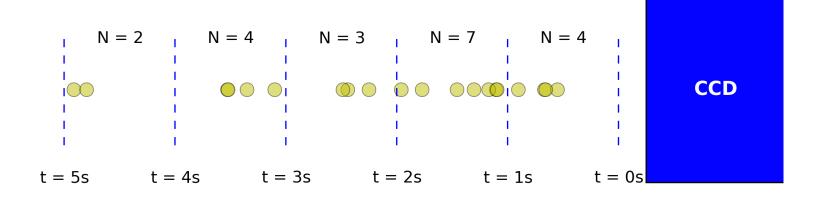
$$d < I_s > /dT \sim -0.5 \mu A/K$$

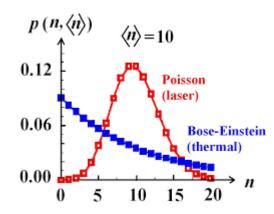
Switching happens very fast, within ~10 ps.

$$\omega_{\rm p}$$
 ~ 100 GHz

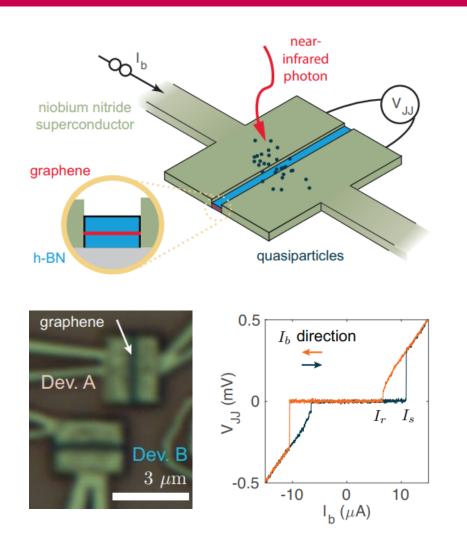
# **Particle-Wave Duality and Photon Statistics**



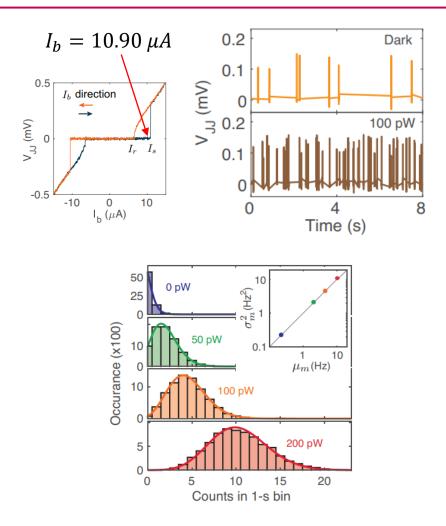




## 1,550-nm NIR Single Photon Detection



[E. Walsh, W. Jung, GHL, ..., Kin Chung Fong, Science 372, 409-412 (2021)]



1. Poisson distribution

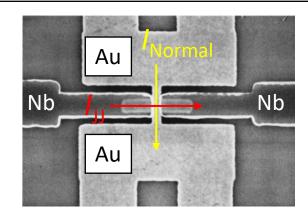
2. Mean count ∝ Laser power

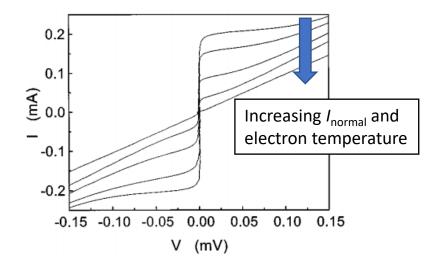


Single photon detection

## **Orthogonal-Terminal Josephson Junction**

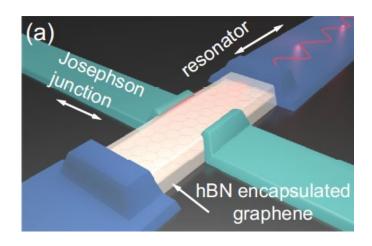
Previous work on orthogonal-terminal JJ

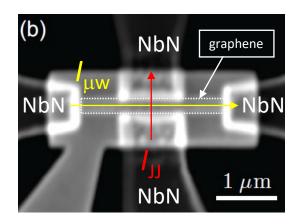




[A. F. Morpurgo et al., APL 72, 23 (1998)]

In this work

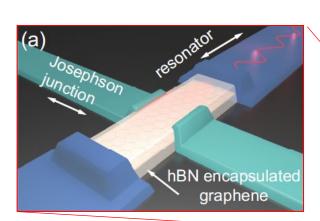


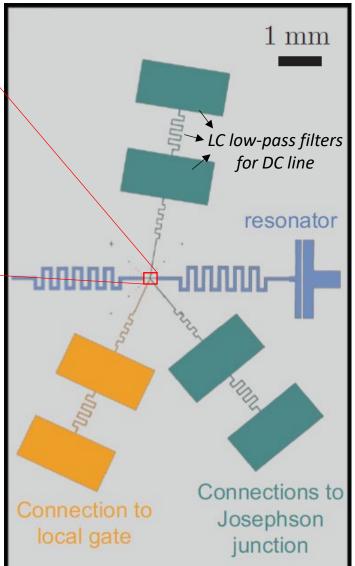


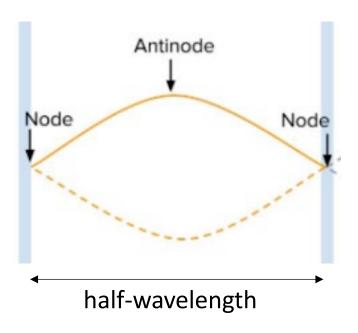
[GHL et al., Nature 586, 42–46 (2020)]



## **GJJ-embedded Resonator**





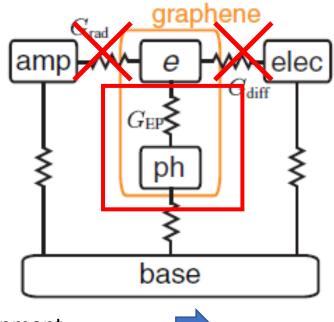


Graphene in current antinode (critically coupled)

Maximum power dissipation in graphene



## **Thermal Circuit**



•  $G_{rad}$ : radiation to environment

very small

• *G*<sub>diff</sub>: hot electron diffusion to electrode



negligible with superconducting electrode

\*Cooper pair doesn't carry momentum.

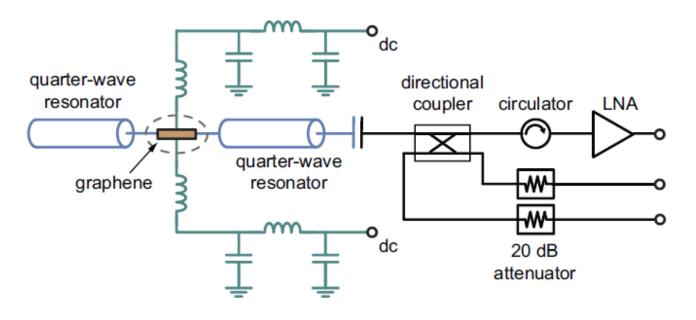
• **G**<sub>EP</sub>: electron-phonon cooling

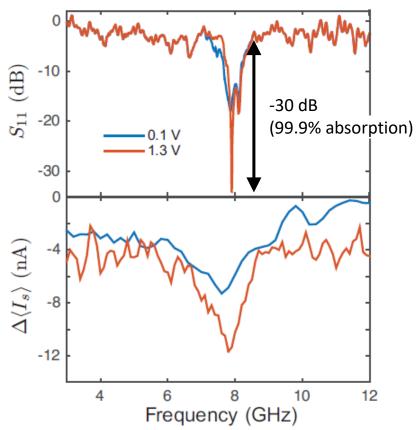


dominant cooling channel

## **Graphene Absorbing Microwave**

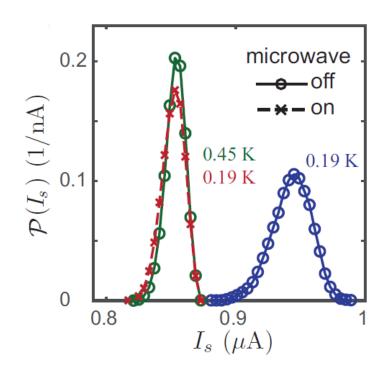
With continuous microwave,  $P_{in}$ =-112 dBm (6 fW),





 $\langle I_s \rangle$  get suppressed at the resonance frequency, f=7.9 GHz.

## **Switching Current Distribution**

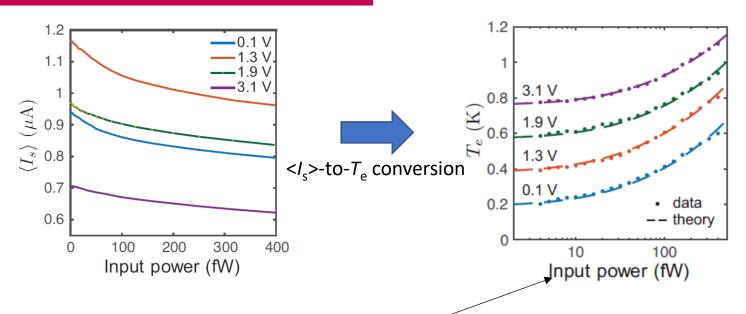


 $P(I_s)$  with microwave input has <u>same shape</u> of  $P(I_s)$  with elevated temperature.



Heated electrons get fully equilibrated.

# Estimation of Electron Temperature, $T_{\rm e}$



Power due to electron-phonon coupling:  $P = \Sigma A \left(T_e^{\delta} - T^{\delta}\right)$ 

- A: Area of graphene
- $\Sigma$ : electron-phonon coupling parameter
- $\delta$ : temperature power law
- T: bath temperature

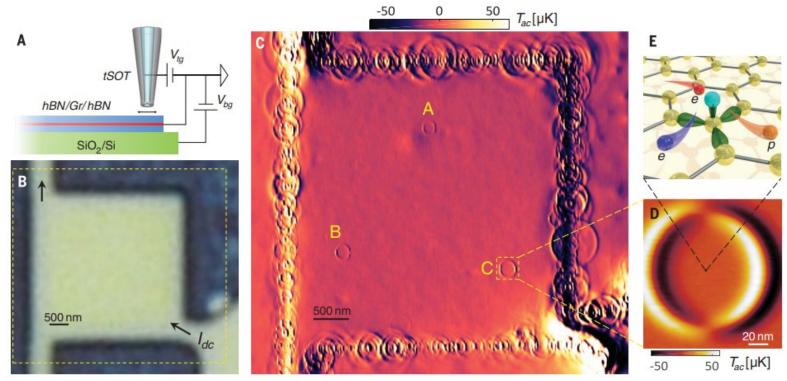
Fitting parameters:  $\delta$ =3,  $\Sigma_{e-ph}$  = 2.14~3.30 Wm<sup>-2</sup>K<sup>-3</sup>

el-ph coupling due to disorder

Large discrepancy. Why?

Estimated  $\Sigma_{\rm e-ph}$  with bulk mobility 20,000 cm<sup>2</sup>/Vs  $\sim$  0.01 Wm<sup>-2</sup>K<sup>-3</sup>

## Cooling Mechanism via Atomic Edge Disorder



[D. Halbertal et al., Science 358, 1303 (2017)]

**Atomic disorders at the edges** could greatly enhance the electron-phonon coupling,  $\Sigma$ .

Theoretically estimated  $\Sigma$  ~ 0.01 Wm<sup>-2</sup>K<sup>-3</sup> << Measured  $\Sigma$  ~ 3 Wm<sup>-2</sup>K<sup>-3</sup>

## **Noise Equivalent Power (NEP)**

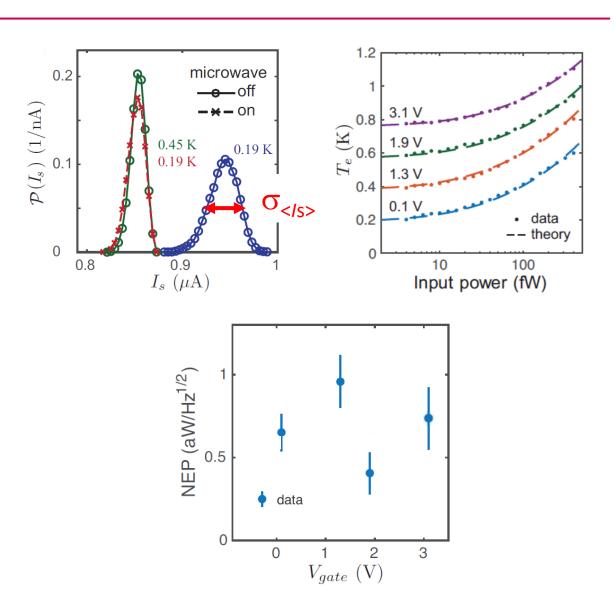
#### Measure of sensitivity of a bolometer

#### **Noise equivalent power** (NEP):

Signal power that gives signal-to-noise ratio of one.

- Minimum power  $P_{\text{min}}$  for changing  $\langle I_s \rangle$  by  $\sigma_{\langle I_s \rangle}$ .  $\rightarrow P_{\text{min}} \sim 11.4 \text{ fW } @ V_{\text{gate}} = 1.9 \text{ V}$
- Time needed for sensing P<sub>min</sub>
  - 1. Resonator input coupling time,  $\tau_{in}$ ~1.6 ns (slowest)
  - 2. Resonator dissipation time ,  $\tau_{dis}^{\sim} \sim 1.3 \text{ ns}$
  - 3. Thermal time constant,  $\tau_{th}^{\sim} \sim 0.6$  ns

$$ightarrow$$
 NEP=  $P_{min}/\sqrt{f_{in}}$ =0.45 aW/Hz $^{1/2}$ 



## **Fundamental Limit of NEP**

Intrinsic thermal fluctuation imposes the fundamental limit of,

- energy resolution,  $\Delta E \sim C_e \sqrt{\langle \Delta T^2 \rangle} = \sqrt{C_e k_B T^2}$
- Fundamental sensitivity of a bolometer,

$$NEP = \sqrt{4G_{th}k_BT^2}$$

$$O = \sqrt{4G_{th}k_BT^$$

Fluctuation of temperature:

$$\sqrt{\langle \Delta T^2 \rangle} = \sqrt{k_B/C_e} \times T$$

e.g.) for  $C_{\rm e}$ =10k<sub>B</sub>, T=0.1 K,  $\Delta E^{\sim}$  6 GHz

We reached the *fundamental limit* 

Expected energy resolution:  $\Delta E = NEP \cdot \sqrt{\tau_{in}} \sim 30 \text{ GHz}$ 

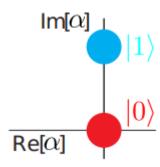
[S. H. Moseley et al., JAP 56, 1257 (1984)]

c.f.) graphene-based bolometer with Johnson noise thermometry, NEP  $^{\sim}$  0.4 pW/Hz<sup>1/2</sup> @ 2 K [K.C. Fong et al., PRX (2012)] NEP  $^{\sim}$  10 pW/Hz<sup>1/2</sup> @ 5 K [D. K. Efetov et al., Nat. Nano. (2018)]

## mw SPD for Qubit Measurement

- Dispersive phase shift readout
- $Q \qquad cos(\omega_c t + \phi_q) \qquad \phi_q = +2$

• Photon-counting readout



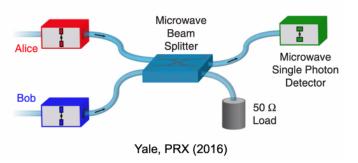
**No need** for room-temperature detection

 $\downarrow$ 

Fast, High-fidelity, **Scalable** measurement

[L.C.G. Govia et al., PRA 90, 062307 (2014)]

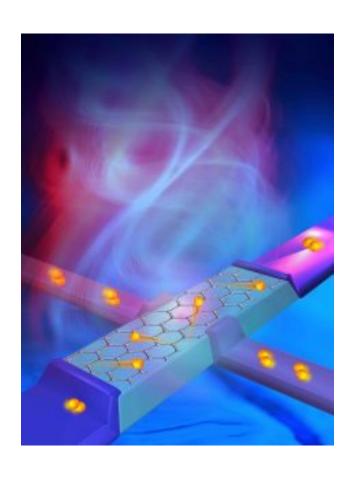
#### • Remote entanglement





## **Acknowledgement**

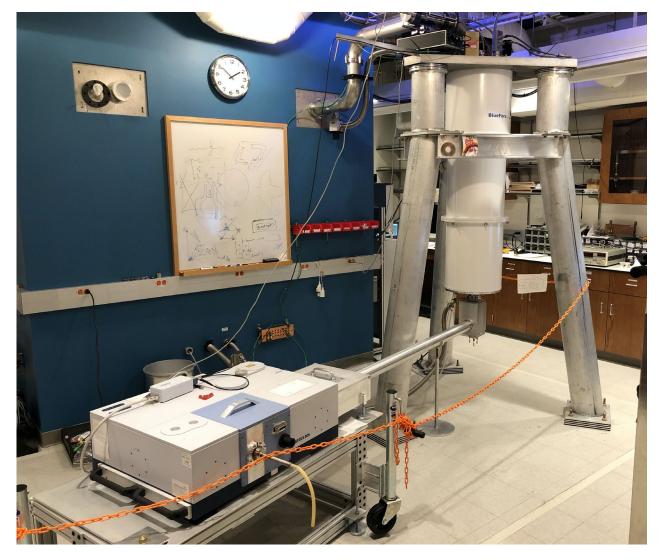
#### **Team**

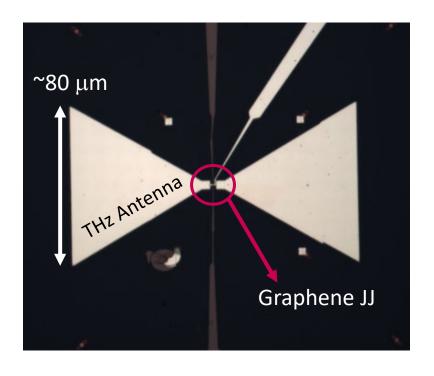


- POSTECH
  - Woochan Jung
- Raytheon BBN technologies
  - Leonardo Ranzani
  - Thomas A. Ohki
  - Kin Chung Fong

- MIT
  - Evan D. Walsh
  - Dmitri K. Efetov
  - Dirk Englund
- NIMS Japan
  - Takashi Taniguchi
  - Kenji Watanabe
- Harvard University
  - Philip Kim

# THz-SPD Project with Washington Univ.

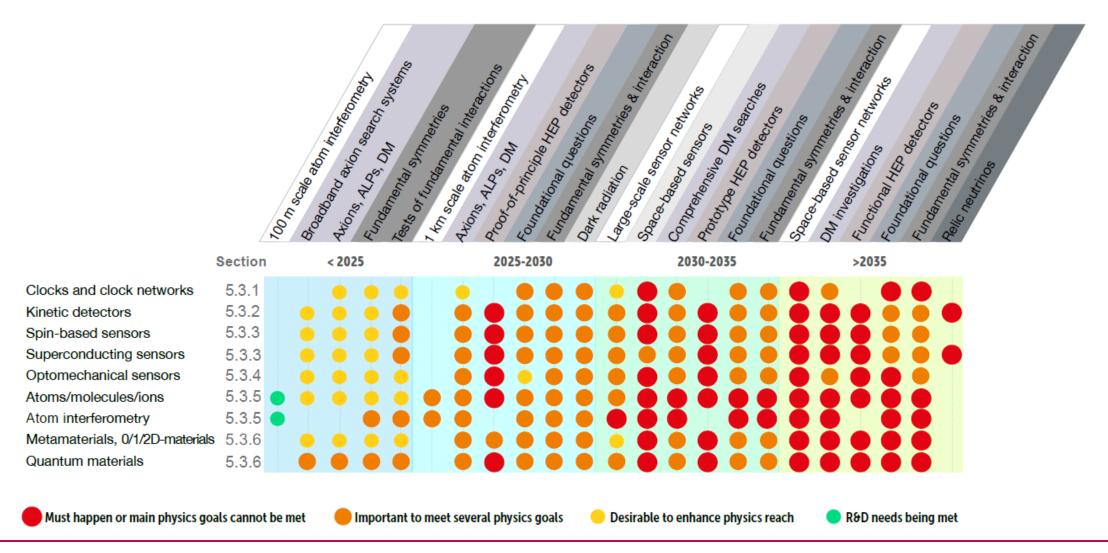




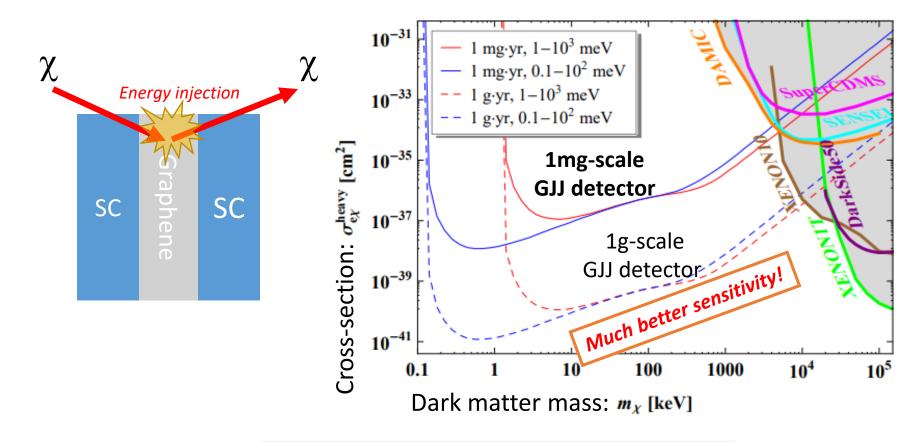
[Setup at Washington University]

## ECFA Detector R&D Roadmap (2021)

The European Committee for Future Accelerators (ECFA)



## **GJJ for Dark Matter Detection?**



How can we make mg-scale GJJ detector?

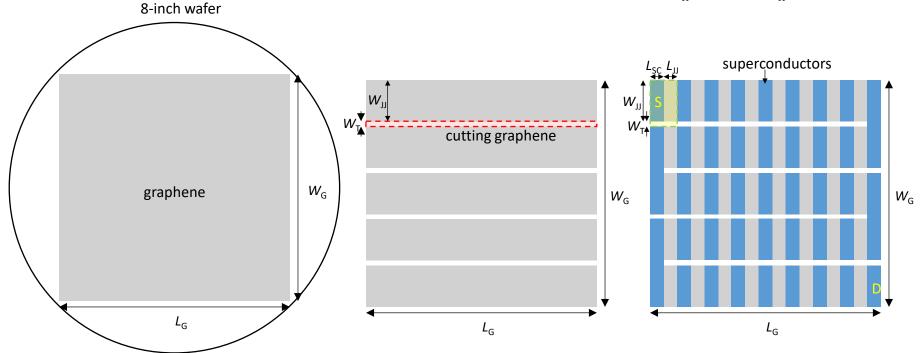
Graphene-Based Bolometer for Detecting keV-Range Superlight Dark Matter, Doojin Kim, Jong-Chul Park, Kin Chung Fong, and **GHL**, arXiv:2002.07821 (submitted)

## **Proposal of 1mg-scale GJJ**

For 1mg-scale GJJ, we need  $\sim$ 870 billion (8.7 x  $10^{11}$ ) GJJs.

\*mass density of graphene: agr =  $7.62 \times 10^{-8}$  g·cm<sup>-2</sup>

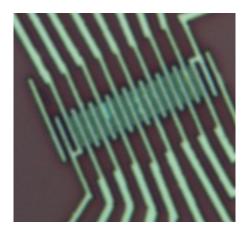
\*GJJ dimension:  $L_{\rm JJ}$ =0.5  $\mu$ m,  $W_{\rm JJ}$ =3  $\mu$ m.



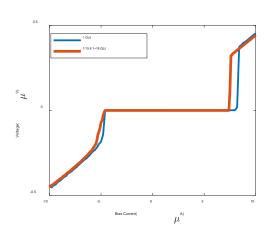
Number of GJJ in a single wafer:  $N_W$  = 5.6 billion (5.6 x 10<sup>9</sup>) Then, we need 150 wafers connected.

<sup>\*</sup> number of transistors in modern integrated circuit chips: 10 billion

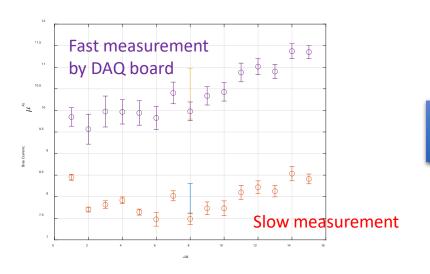
# Uniformity of multiple Graphene Josephson junction (GJJ)



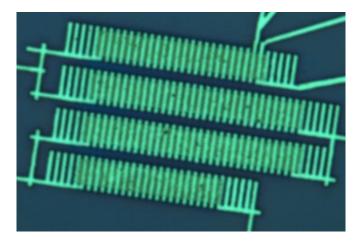
Device optical image



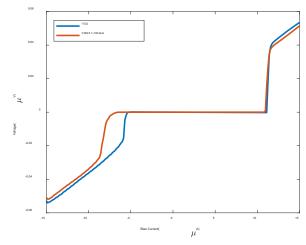
Almost same I-V curve when scaled



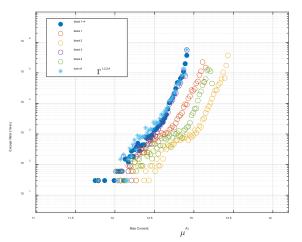
~9% variation in switching current.



Device optical image of ~100 GJJs



Almost same I-V curve when scaled



Escaping rate measurement for four GJJs

 $\sim$ 4% variation in switching current.



## **Summary**

- Graphene of minute heat capacity was utilized for sensitive microwave bolometer.
- Graphene Josephson junction was embedded in the resonator and measured with continuous microwave.
- Achieved fundamentally limited NEP of 0.7 aW/Hz<sup>1/2</sup>, which corresponds to the energy resolution of ~30 GHz (~0.1 meV).
- Various future directions:
   microwave single photon detector (MIT, BBN), detecting ultralight
   dark matter (CNU), terahertz single photon detector (WashU, BBN)

